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Application Number	10594934
Filing Date	2007-10-29
First Named Inventor	Szeles
Art Unit	1752
Examiner Name	Not Yet Assigned
Attorney Docket Number	4375-062621

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SETO et al., Chlorine-related photoluminescence lines in high-resistivity Cl-doped CdTe, Journal of Crystal Growth, pages 271-275, Volume 117, Elsevier Science Publishers B.V.

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